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Kind regards,

Team Nexperia

**Product data sheet** 

# 1. General description

Unidirectional Transient Voltage Suppressor (TVS) in a very small leadless DSN1608-2 (SOD964) package.

#### 2. Features and benefits

- Rated peak pulse current: I<sub>PPM</sub> = 52 A (8/20 µs pulse)
- Rated peak pulse power: P<sub>PPM</sub> = 1900 W (8/20 μs pulse)
- Dynamic resistance R<sub>dvn</sub> = 0.13 Ω
- Reverse current: I<sub>RM</sub> = 0.1 nA typ.
- · Very low package height: 0.29 mm

# 3. Applications

- Power supply protection
- · Industrial application
- Power management

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{RWM}$	reverse standoff voltage	T <sub>amb</sub> = 25 °C		-	-	15	V
I <sub>PPM</sub>	peak pulse current	t <sub>p</sub> = 8/20 μs	[1][2]	-	-	52	Α
		t <sub>p</sub> = 10/1000 μs	[3][2]	-	-	7.5	Α

- [1] In accordance with IEC 61000-4-5 (8/20  $\mu s$  current waveform).
- [2] Measured from pin 1 to pin 2.
- [3] In accordance with IEC 61643-321 (10/1000 µs current waveform).



# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		1 + 2
2	Α	anode	1 2	sym035
			Transparent top view DSN1608-2 (SOD964)	

# 6. Ordering information

### **Table 3. Ordering information**

Type number	Package					
	Name	Description	Version			
PTVS15VZ1USK	DSN1608-2	leadless very small package; 2 terminals; body 1.6 x 0.8 x 0.29 mm	SOD964			

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code
PTVS15VZ1USK	Z6

# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
P <sub>PPM</sub>	peak pulse power	t <sub>p</sub> = 8/20 μs	[1][2]	-	1900	W
		t <sub>p</sub> = 10/1000 μs	[3][2]	-	200	W
I <sub>PPM</sub>	peak pulse current	t <sub>p</sub> = 8/20 μs	[1][2]	-	52	Α
		t <sub>p</sub> = 10/1000 μs	[3][2]	-	7.5	Α
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-40	125	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
ESD maximi	um ratings					
V <sub>ESD</sub>	electrostatic discharge	IEC 61000-4-2; contact discharge	[4][2]	-	30	kV
	voltage	IEC 61000-4-2; air discharge	[4][2]	-	30	kV

- [1] In accordance with IEC 61000-4-5 (8/20 µs current waveform).
- [2] Measured from pin 1 to pin 2.
- [3] In accordance with IEC 61643-321 (10/1000 µs current waveform).
- [4] Device stressed with ten non-repetitive ESD pulses.

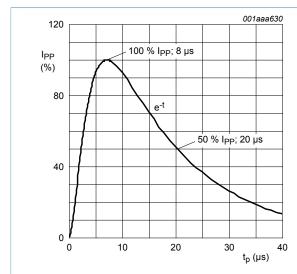


Fig. 1. 8/20 µs pulse waveform according to IEC 61000-4-5

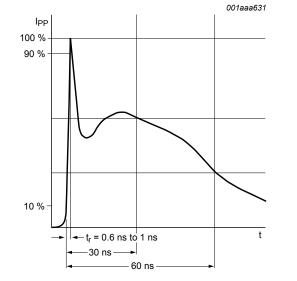
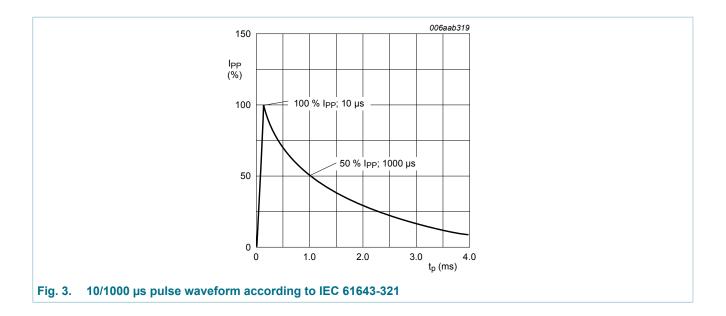


Fig. 2. ESD pulse waveform according to IEC 61000-4-2



### 9. Characteristics

**Table 6. Characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{RWM}$	reverse standoff voltage	T <sub>amb</sub> = 25 °C		-	-	15	V
$V_{BR}$	breakdown voltage	I <sub>R</sub> = 10 mA; T <sub>amb</sub> = 25 °C	[1]	16.7	18	19.4	V
I <sub>RM</sub>	reverse leakage current	V <sub>RWM</sub> = 15 V; T <sub>amb</sub> = 25 °C	[1]	-	0.1	200	nA
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 0 V; T <sub>amb</sub> = 25 °C		-	340	-	pF
V <sub>CL</sub>	clamping voltage	$I_{PPM}$ = 52 A; $T_{amb}$ = 25 °C; $t_p$ = 8/20 µs	[2][1]	-	30.6	36	V
		$I_{PPM}$ = 7.5 A; $T_{amb}$ = 25 °C; $t_p$ = 10/1000 µs	[3][1]	-	22.8	27.4	V
R <sub>dyn</sub>	dynamic resistance	I <sub>R</sub> = 10 A; T <sub>amb</sub> = 25 °C	[4][1]	-	0.13	-	Ω

- Measured from pin 1 to 2.
- [2]
- In accordance with IEC 61000-4-5 (8/20 µs current waveform). In accordance with IEC 61643-321 (10/1000 µs current waveform). [3]
- Non-repetitive current pulse, Transmission Line Pulse (TLP)  $t_p$  = 100 ns; square pulse; ANSI / ESD STM5.5.1-2008.

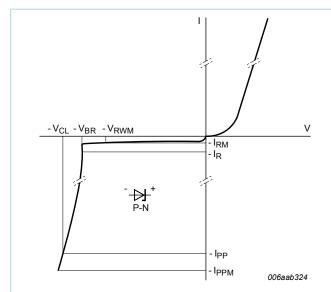


Fig. 4. V-I characteristics for a unidirectional TVS protection diode

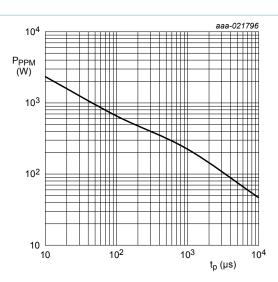


Fig. 5. Rated peak pulse power as a funtion of square pulse duration; typical values

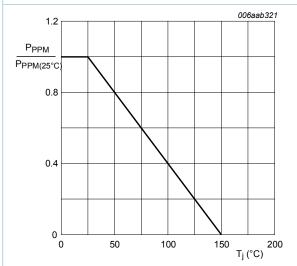


Fig. 6. Relative variation of rated peak pulse power as a function of junction temperature; typical values

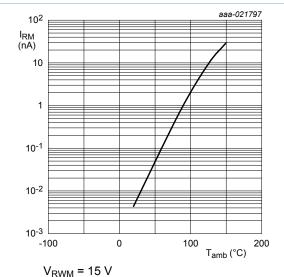


Fig. 7. Relative variation of reverse leakage current as a function of ambient temperature; typical values

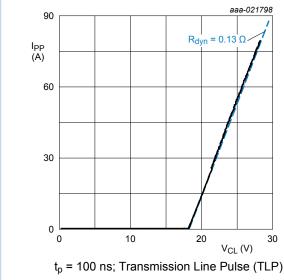


Fig. 8. Positive clamping voltage (TLP); typical values

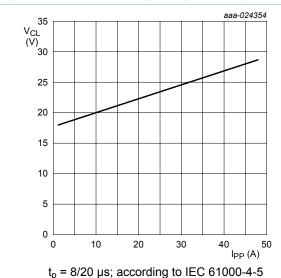
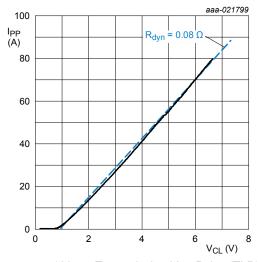


Fig. 10. Positive clamping voltage (8/20 μs pulse); typical values



 $t_p$  = 100 ns; Transmission Line Pulse (TLP)

Negative clamping voltage (TLP); typical values

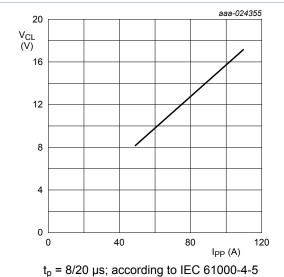
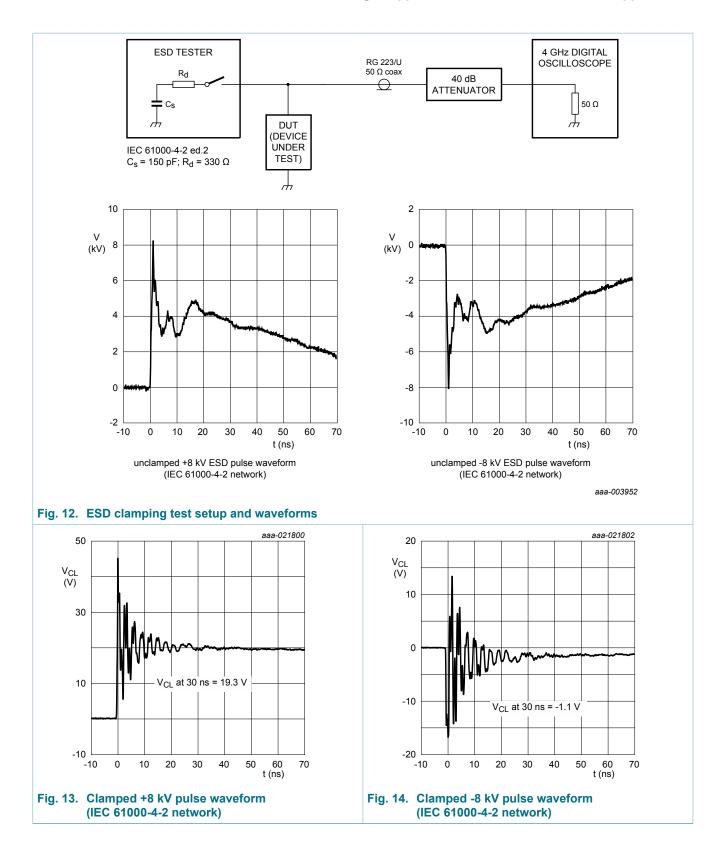
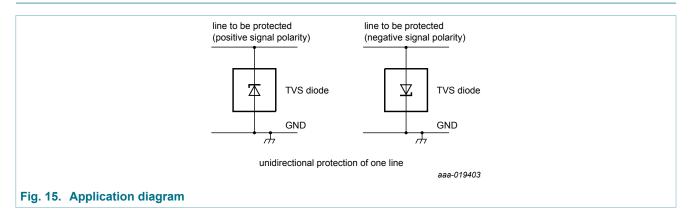


Fig. 11. Negative clamping voltage (8/20 μs pulse); typical values

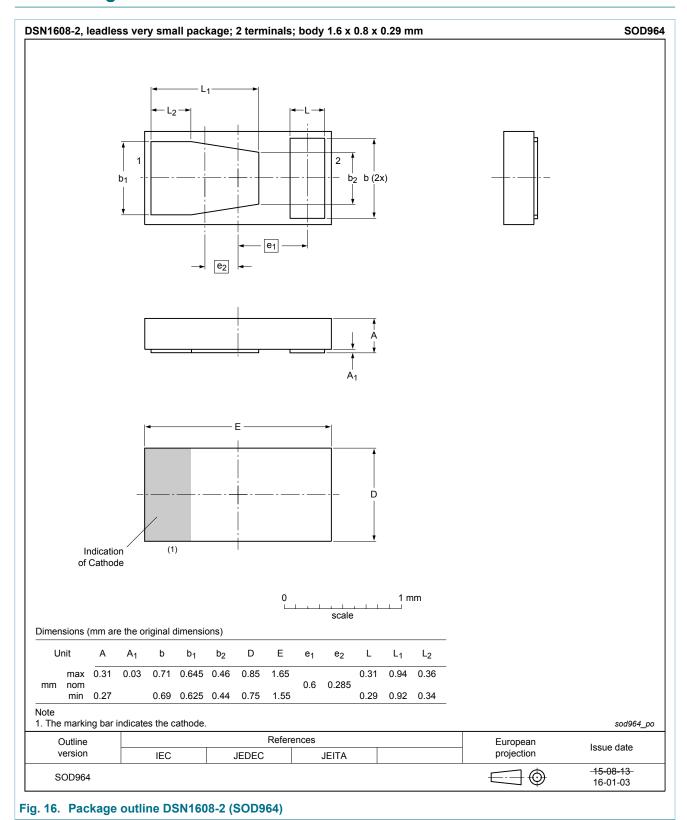
Fig. 9.



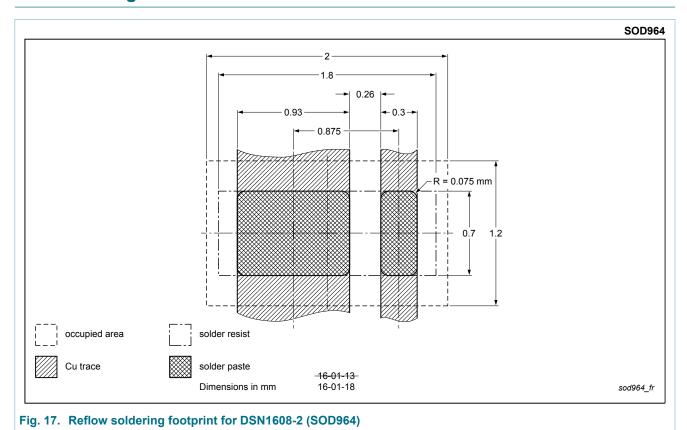
# 10. Application information



# 11. Package outline



# 12. Soldering



# 13. Revision history

#### Table 7. Revision history

Data sheet ID	ta sheet ID Release date Data sheet status Change notice		Change notice	Supersedes			
PTVS15VZ1USK v.2	20160822	Product data sheet	-	PTVS15VZ1USK v.1			
Modifications:	Updated data sheet according to the latest measurements						
PTVS15VZ1USK v.1	20160212	Preliminary data sheet	-	-			

## 14. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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